Monolithic Digital IC



Applications

The LB1688 is a 3-phase brushless motor driver IC ideally suited for use in VTR capstan motor, drum motor drive applications.

Features and Functions

- (1) 120° voltage linear type
- (2) Soft switching type eliminating noises caused by current switching and making the values of external capacitors smaller (comparable to those of chip capacitors)
- (3) On-chip thermal shutdown

Absolute Maximum Ratings at	unit				
Maximum Supply Voltage	V _{CC} max1		20	v	
	V_{CC} max2		7.0	v	
Output Supply Voltage	V _{OUT.V.W.}		22	V	
Output Current	IOUT		1.5	А	
Allowable Power Dissipation	Pd max		2.1	W	
Operating Temperature	Topr		-20 to $+75$	°C	
Storage Temperature	Tstg		-55 to $+125$	°C	
Allowable Operating Condition	ns at Ta = 25°	°C		unit	
Supply Voltage	V_{CC} 1		8.5 to 18	v	
	V_{CC}^2		4.3 to 6.5 V		
Electrical Characteristics at Ta [Power Supply]	$a = 25^{\circ}C, V_{CC}$	$l = 12V, V_{CC}2 = 5V$	min typ	max	unit
Supply Current 1	I _{CC} 1	$V_{\rm C} = 0, R_{\rm L} = \infty$	17	30	mA
Supply Current 2	$I_{CC}2$	$V_{\rm C} = 0$	6.5	9.5	mA

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[Output]			min	typ	max	unit
Output Saturation Voltage	V _{O(sat)} 1	I _{OUT} =0.5A,sink+source		1.6	2.2	v
	$V_{O(sat)}2$	I _{OUT} = 1.0A, sink + source		2.0	3.0	v
Output TRS Voltage	V _{O(sus)}	I _{OUT} =20mA (See note.)	20			V
Output Quiescent Voltage	V _{OQ}	$V_{C} = 0$	5.8	6.1	6.4	v
[Hall Input-Output]						
Hall Amp Input Offset Voltage	V _H offset		- 5		+5	mV
Hall Amp Input Bias Current	I _H bias			1	5	μA
Hall Amp Common-Mode	V _H ch		1.3		3.7	v
Input Voltage Range						
Hall Input-Output Voltage Gain	G _{VHO}			43		dB
[Control-Output]						
Control-Output Drive Gain	G _{VCO}		38	41	44	dB
Control-Output CH Difference	ΔG_{VCO}		-2		+2	dB
[Motor Detection]						
Thermal Shutdown Temperature	T_{SD}	(See note.)	150	180	210	°C
Thermal Shutdown Hysteresis	ΔT_{SD}	(See note.)		15		°Č
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Note : Values shown are design targets only. No measurements have been taken.

Equivalent Circuit Block Diagram

Unit (resistance: Ω , capacitance: F)



LB1688

Pin Assignment



Note : All FRAME pins are connected to GND.

Pin Description

Pin Name	Pin No.	Description				
U _{IN} 1, U _{IN} 2	3,4	U phase hall element input pin. 'H' of logic : $V_{IN}1 > V_{IN}2$				
V _{IN} 1, V _{IN} 2	1,2	/ phase hall element input pin. 'H' of logic : $V_{IN}1 > V_{IN}2$				
W _{IN} 1, W _{IN} 2	29,30	/ phase hall element input pin. 'H' of logic : $V_{IN}1 > V_{IN}2$				
U _{OUT}	11	U phase output pin				
V _{OUT}	12	V phase output pin				
WOUT	13	W phase output pin				
V _{CC} 1	10	Power supply pin for applying output				
V _{CC} 2	16	Power supply pin for applying voltage to each section other than output section. This voltage must be stabilized to be free from ripple, noise, etc.				
Rf	14	Output current detect pin. By connecting Rf across this pin and GND pin, output current is detected as voltage. The result is used to control the overcurrent protection circuit.				
CD	26	Pin for fetching current (voltage) detected with Rf. Takes feedback from Rf to reduce output voltage gain. Ground when not in use.				
FC	5	Frequency characteristic correction				
V _C	25	Speed-phase control pin Control is of voltage-controlled type that controls output voltage.				
V _{CREF}	21	Control reference voltage				
GND	6	GND for other than output				
		Minimum potential of output transistor is at Rf pin.				
F/RC	27	Forward/reverse control pin By setting this pin to 'H' (more than 2.0V)/'L' (less than 0.3V), truth value is changed to perform forward/reverse rotation.				

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	Source			Input		Forward/Reverse Contro					
			Sink	U	v	w	F/RC				
•	W phase	→	V phase	н	н	L	L				
1	V phase	→	W phase	пп	LL LL	н					
2	W phase	>	U phase		L	,	L				
6	U phase	→	W phase	rı	н		L	Н			
3	V phase	→	W phase		,	н	L				
J	W phase	→	V phase	L	L	Ь	Ч	Ц	L	п	н
4	U phase		V phase	L	н	L	L				
4	V phase	→	U phase	Г			Н				
5	V phase	→	U phase	н		н	L				
Ø	U phase		V phase	п	L	п	н				
6	U phase	→	W phase			, <u>, , , , , , , , , , , , , , , , , , </u>	L				
Ð	W phase	→	U phase	L	н	н	Н				

Input:

H: High level. One of the inputs should have a potential at least 0.2V higher than the other.

L: Low level. One of the inputs should have a potential at least 0.2V lower than the other.

Forward/reverse control :

H : 2.0 to V_{CC}2

L:0 to 0.3V

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